

## SN74LVC1G08-Q1

#### SCES556F-MARCH 2004-REVISED APRIL 2008

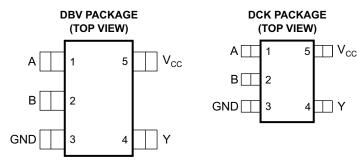
## SINGLE 2-INPUT POSITIVE-AND GATE

#### **FEATURES**

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- Qualified for Automotive Applications
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 3.6 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode
  Operation

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

#### **DESCRIPTION/ORDERING INFORMATION**

The SN74LVC1G08 performs the Boolean function  $A \bullet B$  or  $Y = \overline{A + B}$  in positive logic.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### **ORDERING INFORMATION**<sup>(1)</sup>

| T <sub>A</sub> | PACKAG             | E <sup>(2)</sup> | ORDERABLE PART NUMBER | TOP-SIDE MARKING <sup>(3)</sup> |
|----------------|--------------------|------------------|-----------------------|---------------------------------|
| 40°C to 125°C  | SOT (SOT-23) – DBV | Reel of 3000     | SN74LVC1G08QDBVRQ1    | C08_                            |
| –40°C to 125°C | SOT (SC-70) – DCK  | Reel of 3000     | SN74LVC1G08QDCKRQ1    | CE_                             |
| –40°C to 85°C  | SOT (SOT-23) – DBV | Reel of 3000     | SN74LVC1G08IDBVRQ1    | C08_                            |
|                | SOT (SC-70) – DCK  | Reel of 3000     | SN74LVC1G08IDCKRQ1    | CE_                             |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

|      |     | III BEE |
|------|-----|---------|
| INPL | JTS | OUTPUT  |
| Α    | В   | Y       |
| Н    | Н   | Н       |
| L    | Х   | L       |
| Х    | L   | L       |

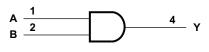
FUNCTION TABLE



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### LOGIC DIAGRAM (POSITIVE LOGIC)



#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                  |  |                                       | MIN  | MAX                   | UNIT |
|------------------|--|---------------------------------------|------|-----------------------|------|
| $V_{CC}$         | Supply voltage range                                     |                                       | -0.5 | 6.5                   | V    |
| VI               | Input voltage range <sup>(2)</sup>                       |                                       | -0.5 | 6.5                   | V    |
| Vo               | Voltage range applied to any output in the high-impeda   | nce or power-off state <sup>(2)</sup> | -0.5 | 6.5                   | V    |
| Vo               | Voltage range applied to any output in the high or low s | state <sup>(2)(3)</sup>               | -0.5 | V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>  | Input clamp current                                      | V <sub>1</sub> < 0                    |      | -50                   | mA   |
| I <sub>OK</sub>  | Output clamp current                                     | V <sub>O</sub> < 0                    |      | -50                   |      |
| I <sub>O</sub>   | Continuous output current                                |                                       |      | ±50                   | mA   |
|                  | Continuous current through V <sub>CC</sub> or GND        |                                       |      | ±100                  | mA   |
| 0                | Deckage thermal impedance <sup>(4)</sup>                 | DBV package                           |      | 206                   | 0000 |
| $\theta_{JA}$    | Package thermal impedance <sup>(4)</sup>                 | DCK package                           |      | 252                   | °C/W |
| T <sub>stg</sub> | Storage temperature range                                |                                       | -65  | 150                   | °C   |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

2

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#### **Recommended Operating Conditions**<sup>(1)</sup>

|                 |                                    |  | MIN                 | MAX                  | UNIT |
|-----------------|------------------------------------|--|---------------------|----------------------|------|
|                 | Cumplus selfana                    | Operating                                  | 1.65                | 5.5                  | V    |
| V <sub>CC</sub> | Supply voltage                     | Data retention only                        | 1.5                 |                      | V    |
|                 |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V         | $0.65 	imes V_{CC}$ |                      |      |
|                 | L Park Jacob Served and the ser    | V <sub>CC</sub> = 2.3 V to 2.7 V           | 1.7                 |                      |      |
| V <sub>IH</sub> | High-level input voltage           | $V_{CC} = 3 V$ to 3.6 V                    | 2                   |                      | V    |
|                 |                                    | $V_{CC} = 4.5 V$ to 5.5 V                  | $0.7 \times V_{CC}$ |                      |      |
|                 |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V         |                     | $0.35 \times V_{CC}$ |      |
| .,              |                                    | V <sub>CC</sub> = 2.3 V to 2.7 V           |                     | 0.7                  | V    |
| V <sub>IL</sub> | Low-level input voltage            | $V_{CC} = 3 V$ to 3.6 V                    |                     | 0.8                  | V    |
|                 |                                    | $V_{CC} = 4.5 V$ to 5.5 V                  |                     | $0.3 \times V_{CC}$  |      |
| VI              | Input voltage                      |  | 0                   | 5.5                  | V    |
| Vo              | Output voltage                     |  | 0                   | V <sub>CC</sub>      | V    |
|                 |                                    | V <sub>CC</sub> = 1.65 V                   |                     | -4                   |      |
|                 |                                    | V <sub>CC</sub> = 2.3 V                    |                     | -8                   |      |
| I <sub>OH</sub> | High-level output current          | <u> </u>                                   |                     | -16                  | mA   |
|                 |                                    | $V_{CC} = 3 V$                             |                     | -24                  |      |
|                 |                                    | V <sub>CC</sub> = 4.5 V                    |                     | -32                  |      |
|                 |                                    | V <sub>CC</sub> = 1.65 V                   |                     | 4                    |      |
|                 |                                    | V <sub>CC</sub> = 2.3 V                    |                     | 8                    |      |
| l <sub>OL</sub> | Low-level output current           | $V_{CC} = 3 V$                             |                     | 16                   | mA   |
|                 |                                    | $v_{CC} = 3 v$                             |                     | 24                   |      |
|                 |                                    | $V_{CC} = 4.5 V$                           |                     | 32                   |      |
|                 |                                    | $V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V   |                     | 20                   |      |
| Δt/Δv           | Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ |                     | 10                   | ns/V |
|                 |                                    | $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$   |                     | 5                    |      |
| т               |                                    | Q-suffix devices                           | -40                 | 125                  | °C   |
| T <sub>A</sub>  | Operating free-air temperature     | I-suffix devices                           | -40                 | 85                   | -C   |

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

3



#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER        | TEST C                                | ONDITIONS                              | V <sub>cc</sub>   | MIN TYP <sup>(1</sup>  | MAX  | UNIT |
|------------------|---------------------------------------|--|-------------------|------------------------|------|------|
|                  | 1 100 4                               | $T_A = -40^{\circ}C$ to $125^{\circ}C$ | - 1.65 V to 5.5 V | V <sub>CC</sub> – 0.15 |      |      |
|                  | I <sub>OH</sub> = −100 μA             | $T_A = -40^{\circ}C$ to $85^{\circ}C$  |                   | V <sub>CC</sub> – 0.1  |      |      |
|                  | I <sub>OH</sub> = -4 mA               |  | 1.65 V            | 1.2                    |      |      |
| V <sub>OH</sub>  | I <sub>OH</sub> = -8 mA               |  | 2.3 V             | 1.9                    |      | V    |
|                  | I <sub>OH</sub> = -16 mA              |  | - 3 V             | 2.4                    |      |      |
|                  | I <sub>OH</sub> = -24 mA              |  | 3 V               | 2.3                    |      |      |
|                  | I <sub>OH</sub> = -32 mA              |  | 4.5 V             | 3.8                    |      |      |
|                  | I <sub>OL</sub> = 100 μA              |  | 1.65 V to 5.5 V   |                        | 0.1  |      |
|                  | $I_{OL} = 4 \text{ mA}$               |  | 1.65 V            |                        | 0.45 |      |
| M                | I <sub>OL</sub> = 8 mA                |  | 2.3 V             |                        | 0.3  | v    |
| V <sub>OL</sub>  | I <sub>OL</sub> = 16 mA               |  | - 3 V             |                        | 0.4  | V    |
|                  | I <sub>OL</sub> = 24 mA               |  | - 3 V             |                        | 0.55 |      |
|                  | I <sub>OL</sub> = 32 mA               |  | 4.5 V             |                        | 0.55 |      |
| II A or B inputs | V <sub>I</sub> = 5.5 V or GND         |  | 0 to 5.5 V        |                        | ±5   | μΑ   |
| l <sub>off</sub> | $V_{\rm I}$ or $V_{\rm O}$ = 5.5 V    |  | 0                 |                        | ±10  | μΑ   |
| I <sub>CC</sub>  | $V_{I} = 5.5 V \text{ or GND},$       | I <sub>O</sub> = 0                     | 1.65 V to 5.5 V   |                        | 10   | μA   |
| ΔI <sub>CC</sub> | One input at V <sub>CC</sub> – 0.6 V, | Other inputs at $V_{CC}$ or GND        | 3 V to 5.5 V      |                        | 500  | μΑ   |
| C <sub>i</sub>   | $V_{I} = V_{CC}$ or GND               |  | 3.3 V             | 2                      | ŀ    | pF   |

(1) All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.

#### **Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF or 50 pF (unless otherwise noted) (see Figure 1)

|                 |                 | TO<br>(OUTPUT) | T <sub>A</sub> = −40°C to 125°C     |     |                                    |     |                                    |     |                                  |     |      |  |
|-----------------|-----------------|----------------|-------------------------------------|-----|------------------------------------|-----|------------------------------------|-----|----------------------------------|-----|------|--|
| PARAMETER       | FROM<br>(INPUT) |                | V <sub>CC</sub> = 1.8 V<br>± 0.15 V |     | V <sub>CC</sub> = 2.5 V<br>± 0.2 V |     | V <sub>CC</sub> = 3.3 V<br>± 0.3 V |     | V <sub>CC</sub> = 5 V<br>± 0.5 V |     | UNIT |  |
|                 |                 |                | MIN                                 | MAX | MIN                                | MAX | MIN                                | MAX | MIN                              | MAX |      |  |
| t <sub>pd</sub> | A or B          | Y              | 1                                   | 10  | 1                                  | 7.5 | 1                                  | 6.5 | 1                                | 6   | ns   |  |

#### **Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF or 50 pF (unless otherwise noted) (see Figure 1)

|                 |                 |                | $T_A = -40^{\circ}C$ to $85^{\circ}C$ |     |                                    |     |                                    |     |                                  |     |      |  |
|-----------------|-----------------|----------------|---------------------------------------|-----|------------------------------------|-----|------------------------------------|-----|----------------------------------|-----|------|--|
| PARAMETER       | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = 1.8 V<br>± 0.15 V   |     | V <sub>CC</sub> = 2.5 V<br>± 0.2 V |     | V <sub>CC</sub> = 3.3 V<br>± 0.3 V |     | V <sub>CC</sub> = 5 V<br>± 0.5 V |     | UNIT |  |
|                 |                 |                | MIN                                   | MAX | MIN                                | MAX | MIN                                | MAX | MIN                              | MAX |      |  |
| t <sub>pd</sub> | A or B          | Y              | 2.4                                   | 8   | 1.1                                | 5.5 | 1                                  | 4.5 | 1                                | 4   | ns   |  |

#### **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

4

|                   | PARAMETER                     | TEST CONDITIONS | V <sub>CC</sub> = 1.8 V | $V_{CC} = 2.5 V$ | V <sub>CC</sub> = 3.3 V | $V_{CC} = 5 V$ | UNIT |  |
|-------------------|-------------------------------|-----------------|-------------------------|------------------|-------------------------|----------------|------|--|
|                   | FARAMETER                     | TEST CONDITIONS | TYP                     | ТҮР              | YP TYP T                |                | UNIT |  |
| $\mathbf{C}_{pd}$ | Power dissipation capacitance | f = 10 MHz      | 21                      | 24               | 26                      | 31             | pF   |  |

## SN74LVC1G08-Q1

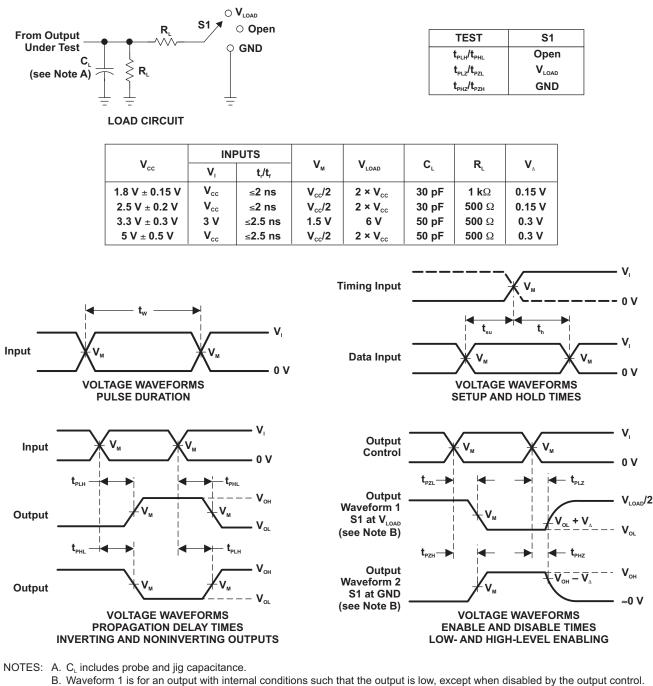
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ÈXAS

**INSTRUMENTS** 





B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
 Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>o</sub> = 50 Ω.

- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{\mbox{\tiny PLZ}}$  and  $t_{\mbox{\tiny PHZ}}$  are the same as  $t_{\mbox{\tiny dis}}$
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms



11-Apr-2013

#### PACKAGING INFORMATION

| Orderable Device   | Status | Package Type | Package | Pins | Package | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Top-Side Markings | Samples |
|--------------------|--------|--------------|---------|------|---------|----------------------------|------------------|--------------------|--------------|-------------------|---------|
|                    | (1)    |              | Drawing |      | Qty     | (2)                        |                  | (3)                |              | (4)               |         |
| SN74LVC1G08IDCKRQ1 | ACTIVE | SC70         | DCK     | 5    | 3000    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 85    | CEO               | Samples |
| SN74LVC1G08QDBVRQ1 | ACTIVE | SOT-23       | DBV     | 5    | 3000    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | C08O              | Samples |
| SN74LVC1G08QDCKRQ1 | ACTIVE | SC70         | DCK     | 5    | 3000    | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | CEO               | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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## PACKAGE OPTION ADDENDUM

11-Apr-2013

#### OTHER QUALIFIED VERSIONS OF SN74LVC1G08-Q1 :

• Catalog: SN74LVC1G08

• Enhanced Product: SN74LVC1G08-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal |                 |                    |   |      |                          |                          |            |            |            |            |           |                  |  |
|-----------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|--|
| Device                      | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |  |
| SN74LVC1G08IDCKRQ1          | SC70            | DCK                | 5 | 3000 | 179.0                    | 8.4                      | 2.2        | 2.5        | 1.2        | 4.0        | 8.0       | Q3               |  |
| SN74LVC1G08QDBVRQ1          | SOT-23          | DBV                | 5 | 3000 | 179.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |  |
| SN74LVC1G08QDCKRQ1          | SC70            | DCK                | 5 | 3000 | 179.0                    | 8.4                      | 2.2        | 2.5        | 1.2        | 4.0        | 8.0       | Q3               |  |

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

3-Aug-2017



\*All dimensions are nominal

| Device             | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LVC1G08IDCKRQ1 | SC70         | DCK             | 5    | 3000 | 203.0       | 203.0      | 35.0        |
| SN74LVC1G08QDBVRQ1 | SOT-23       | DBV             | 5    | 3000 | 203.0       | 203.0      | 35.0        |
| SN74LVC1G08QDCKRQ1 | SC70         | DCK             | 5    | 3000 | 203.0       | 203.0      | 35.0        |

## DBV 5

# **GENERIC PACKAGE VIEW**

# SOT-23 - 1.45 mm max height SMALL OUTLINE TRANSISTOR



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





# **PACKAGE OUTLINE**

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC MO-178.



# **EXAMPLE BOARD LAYOUT**

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# **EXAMPLE STENCIL DESIGN**

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



<sup>6.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# **PACKAGE OUTLINE**

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC MO-178.



# **EXAMPLE BOARD LAYOUT**

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# **EXAMPLE STENCIL DESIGN**

## SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



<sup>6.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AA.



## LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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